## NSN 5961-00-999-5134

Transistor - Page 1 of 1

**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-999-5134 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc and 60.0 collector to emitter voltage, dc and 4.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 0.50 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No